

PREMIUM HG425U-SM12 405-425Wp

MONOFACIAL
SHINGI FD PERC



G12 PERC Shingled Technology provides ultra-high efficiency with better performance in low irradiation. Maximizes installation capacity in limited space.



Regional value creation, made without lead and produced using 100% renewable energy.



Selected encapsulating material and stringent production process control ensure the product is highly PID resistant and snail trails free



Optimized system performance due to module level current sorting



Highly transparent self-cleaning glass brings additional yield and easy maintenance



Various tests under harsh environmental conditions such as ammonia and salt-mist passed.



Higon Reliable Quality

- World-class manufacturer of crystalline silicon photovoltaic modules
- Fully automatic facility and world-class technology
- Rigorous quality control to meet the highest standard: ISO 9001, ISO 14001 and ISO 45001
- Long term reliability tests
- 3X100% EL inspeciton ensuring defect-free modules







THE IDEAL SOLUTION FOR:



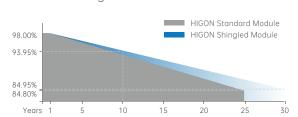
Performance Warranty

15 Years Product Warranty

30 Years Linear Power Warranty

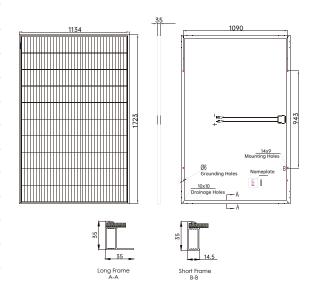
2% Degradation in 1st year

4.5% Annual Degradation Over 30 Years



Mechanical Characteristics

Solar Cell	Monocrystalline silicon 210mm	
No. of Cells	256 (8×32)	
Dimensions	1723×1134×35mm	
Weight	20.9 kg	
Front Glass	High transparency solar glass 3.2mm	
Cable	4.0mm², 300mm/1200mm	
Junction Box	IP68 rated(3 bypass diodes)	
Connector	MC Compatible	
Operating Module Temperature	-40°C to +85°C	
Maximum System Voltage	1500 VDC (IEC)	
Maximum Series Fuse Rating	25A	
Wind/ Snow Load	2400Pa/ 5400Pa	



Electrical Characteristics

POWER CLASS	410	415	420	425
Testing Condition	STC NMO	T STC NM	IOT STC NMOT	STC NMOT
Maximum Power(Pmax/W)	410 307	415 31	11 420 315	425 320
Operating Voltage(Vmp/V)	38.31 34.3	1 38.32 34.	.41 38.44 34.51	38.56 34.62
Operating Current(Imp/A)	10.71 8.95	10.83 9.0	04 10.93 9.13	11.02 9.24
Open-Circuit Voltage(Voc/V)	43.61 41.2	3 43.66 41.	33 43.68 41.44	43.72 41.55
Short-Circuit Current(Isc/A)	11.44 9.40	11.53 9.4	49 11.54 9.59	12.01 9.68
Module Efficiency(%)	21.0	21.3	21.5	21.8

STC: Irradiance 1000 W/m2, module temperature 25 °C, AM=1.5; NMOT: Irradiance 800 W/m2 , ambient temperature 20 °C, AM=1.5, wind speed 1 m/s; Tolerance of Pmax is within +/- 3%;

Temperature Characteristics

Nominal Module Operating Temperature (NMOT)	43 ± 2 °C
Temperature Coefficient of Pmax	-0.36%/°C
Temperature Coefficient of Voc	-0.28%/°C
Temperature Coefficient of Isc	+0.05%/°C

Packing Configuration











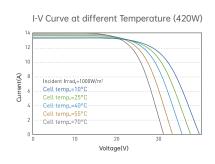




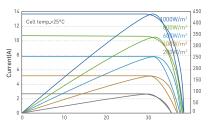


Notice: All data and specifications are preliminary and subject to change without notice.

Graphs



I-V/P-V Curve at different Irradiation (420W)



Contact Us for More Information